## NSN 5961-01-372-4113

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-372-4113 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.185 inches **Terminal Length:** Between 1.000 inches and 1.300 inches **Overall Diameter:** Between 0.085 inches and 0.140 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 18.2 working peak reverse voltage and 22.8 breakdown voltage, instantaneous **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 1.00 microamperes forward current, average peak and 15.00 amperes source cutoff current pascal **Power Rating Per Characteristic:** 500.0 watts any acceptable major **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Terminal surface option silver **Precious Material:** Silver **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/516 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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